NSN 5961-00-945-9596

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-945-9596
Inclosure Material:
Metal
Overall Length:
0.505 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 breakover voltage, dc
Current Rating Per Characteristic:
25.00 amperes forward current, average watts
Power Rating Per Characteristic:
$500.0 \ milliwatts \ small-signal \ input \ power, \ \ common-collector \ blank$
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0